

1 Amp. Silicon Rectifier Diodes

Dimensions in mm. DO-41 (Plastic)

Mounting instructions

- 1. Min. distance from body to soldering point, 4 mm.
- 2. Max. solder temperature, 350°C.
- 3. Max. soldering time, 3.5 sec.
- 4. Do not bend lead at a point closer than 2 mm. to the body.

Voltage 50 to 1000 V.

Current 1.0 A. at 75°C.

- Low cost
- Diffused junction
- High current capability
- The plastic material carries U/L recognition 94 V-0
- Terminals: Axial Leads
- Polarity: Color band denotes cathode

Maximum Ratings, according to IEC publication No. 134

		1N 4001F	1N 4002F	1N 4003F	1N 4004F	1N 4005F	1N 4006F	1N 4007F
V_{RRM}	Peak recurrent reverse voltage (V)	50	100	200	400	600	800	1000
$I_{F(AV)}$	Forward current at Tamb = 75°C	1 A						
I_{FRM}	Recurrent peak forward current	10 A						
I_{FSM}	8.3 ms. peak forward surge current	30 A						
T_{j}	Operating temperature range	− 65 to + 150 °C						
$T_{ m stg}$	Storage temperature range	- 65 to + 150 °C						

Electrical Characteristics at Tamb = 25°C

V _F	Max. forward voltage drop at $I_{\scriptscriptstyle F}=1$ A	1.1V			
$I_{\mathbb{R}}$	Max. reverse current at V _{RRM} at 25°C at 100°C	5 μ A 50 μ A			
R _{thj-a}	Max. thermal resistance (I = 10 mm.)	50° C/W			



Characteristic Curves







